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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# **HAT2099H**

# Silicon N Channel Power MOS FET Power Switching

REJ03G1187-0500 (Previous: ADE-208-1432C)

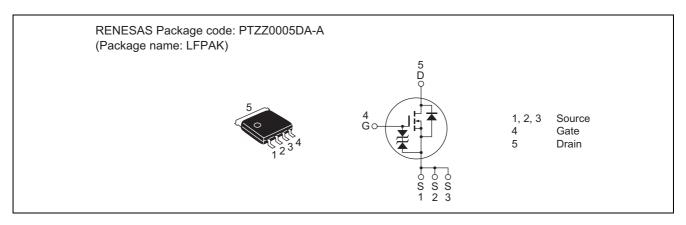
Rev.5.00

Sep 07, 2005

#### **Features**

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance  $R_{DS \; (on)} = 2.9 \; m\Omega \; typ. \; (at \; V_{GS} = 10 \; V) \label{eq:decomposition}$

#### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Value	Unit	
Drain to source voltage	V <sub>DSS</sub>	30	V	
Gate to source voltage	V <sub>GSS</sub>	±20	V	
Drain current	I <sub>D</sub>	50	А	
Drain peak current	I <sub>D (pulse)</sub> Note 1	200	А	
Body-drain diode reverse drain current	I <sub>DR</sub>	50	А	
Avalanche current	I <sub>AP</sub> Note 3	5	А	
Avalanche energy	E <sub>AR</sub> Note 3	2.5	mJ	
Channel dissipation	Pch Note 2	30	W	
Channel temperature	Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Tc = 25 °C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

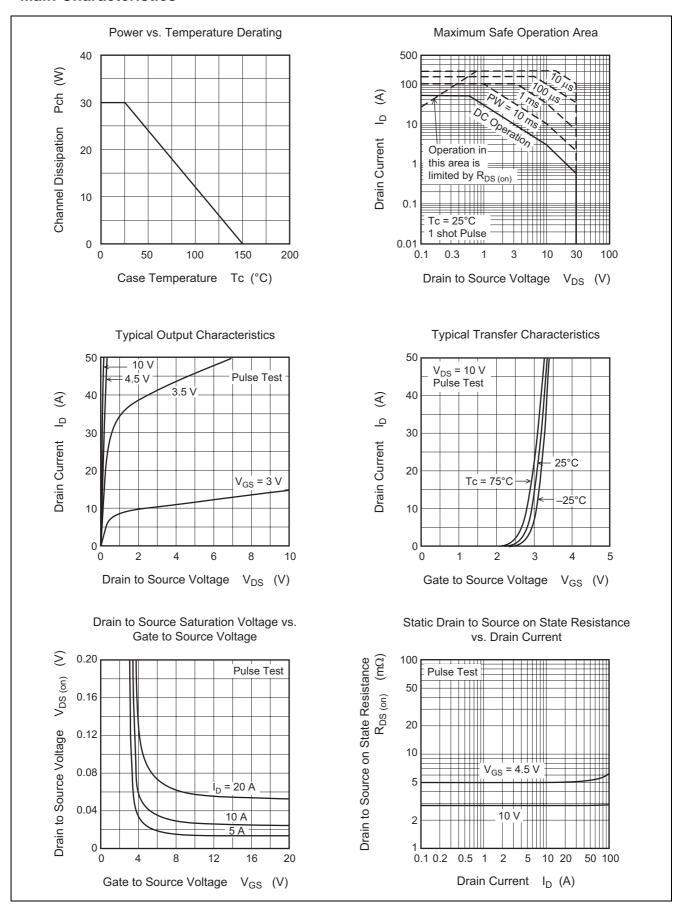
#### **Electrical Characteristics**

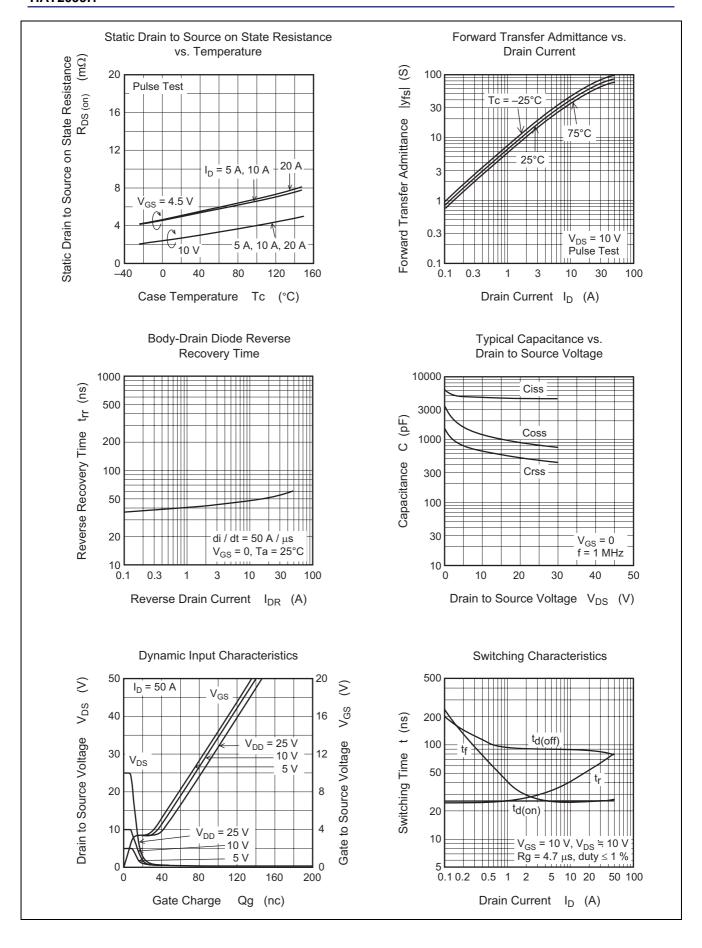
 $(Ta = 25^{\circ}C)$ 

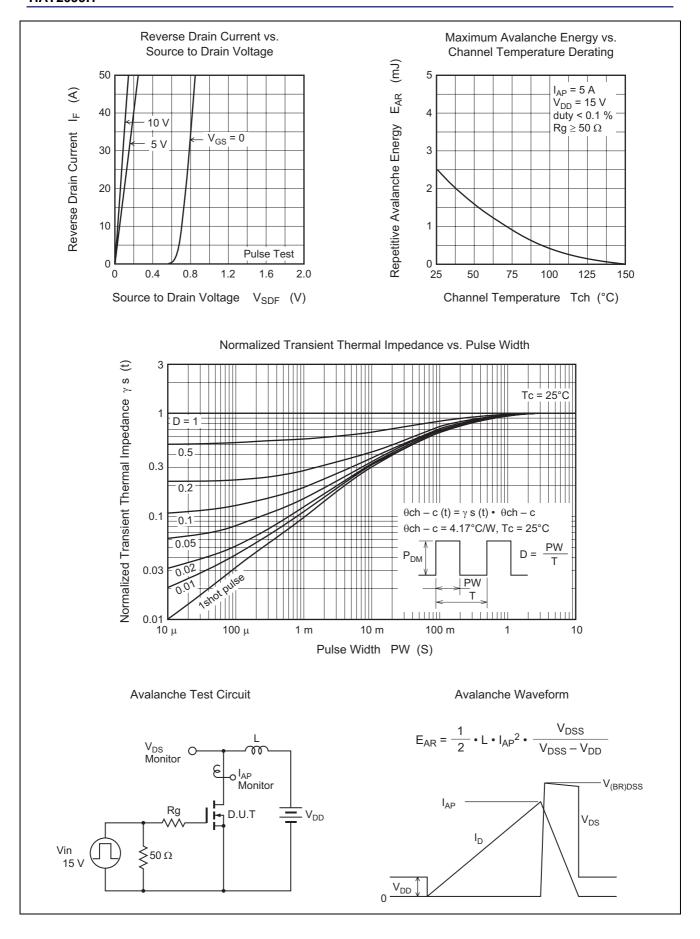
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
	+ -					
Drain to source breakdown voltage	V <sub>(BR) DSS</sub>	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V <sub>(BR)</sub> GSS	±20	_	_	V	$I_G = \pm 100 \mu\text{A},  V_{DS} = 0$
Gate to source leak current	$I_{GSS}$	_	—	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	—	—	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V <sub>GS (off)</sub>	1.0	—	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS (on)</sub>	_	2.9	3.7	mΩ	$I_D = 25 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
	R <sub>DS (on)</sub>	_	5.0	7.3	mΩ	$I_D = 25 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y <sub>fs</sub>	39	65	_	S	$I_D = 25 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	4750	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	1180	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	650	_	pF	f = 1 MHz
Total gate charge	Qg	_	75	_	nC	V <sub>DD</sub> = 10 V
Gate to source charge	Qgs	_	16	_	nC	V <sub>GS</sub> = 10 V
Gate to drain charge	Qgd	_	14	_	nC	I <sub>D</sub> = 50 A
Turn-on delay time	t <sub>d (on)</sub>	_	26	_	ns	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$
Rise time	t <sub>r</sub>	_	60	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	t <sub>d (off)</sub>	_	85	_	ns	$R_L = 0.4 \Omega$
Fall time	t <sub>f</sub>	_	26	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	$V_{DF}$	_	0.85	0.98	V	$I_F = 50 \text{ A}, V_{GS} = 0$ Note 4
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	60	_	ns	$I_F = 50 \text{ A}, V_{GS} = 0$
						di <sub>F</sub> /dt = 50 A/μs

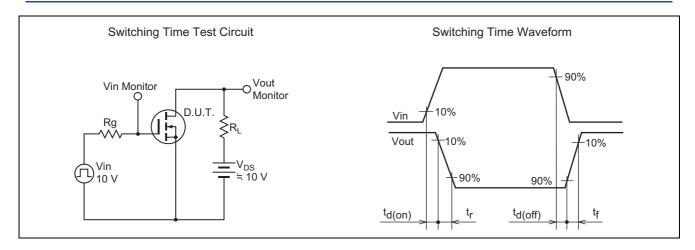
Note: 4. Pulse test

#### **Main Characteristics**

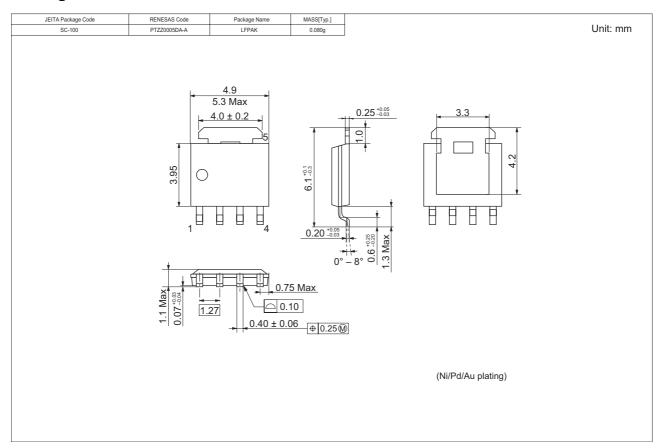








## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
HAT2099H-EL-E	2500 pcs	Taping

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